

550MHz low noise current feedback amplifier

Features

■ Bandwidth: 550MHz in unity gain

■ Quiescent current: 4.1mA

Slew rate: 940V/µsInput noise: 1.5nV/√Hz

■ Distortion: SFDR=-66dBc (10MHz, 1V_{pp})

2.8V_{pp} minimum output swing on 100Ω load for

a 5V supply

■ Tested on 5V power supply

Applications

■ Communication & video test equipment

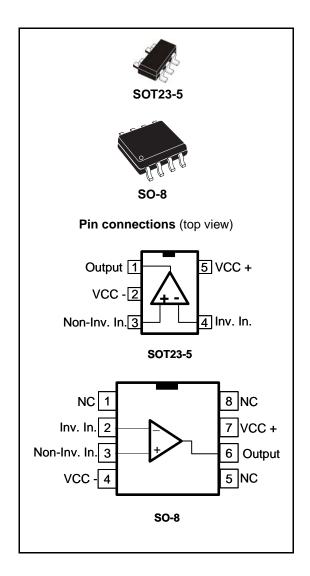
Medical instrumentation

ADC drivers

Description

The TSH350 is a current feedback operational amplifier using a very high-speed complementary technology to provide a bandwidth up to 410MHz while drawing only 4.1mA of quiescent current. With a slew rate of 940V/µs and an output stage optimized for driving a standard $100\Omega \, \text{load},$ this circuit is highly suitable for applications where speed and power-saving are the main requirements.

The TSH350 is a single operator available in the tiny SOT23-5 and SO-8 plastic packages, saving board space as well as providing excellent thermal and dynamic performance.



1 Absolute maximum ratings

Table 1. Absolute maximum ratings (AMR)

| Symbol | Parameter | Value | Unit | |
|-------------------|---|-------------|------|--|
| V _{CC} | Supply voltage ⁽¹⁾ | 6 | V | |
| V _{id} | Differential input voltage ⁽²⁾ | +/-0.5 | V | |
| V _{in} | Input voltage range ⁽³⁾ | +/-2.5 | V | |
| T _{stg} | Storage temperature | -65 to +150 | °C | |
| Tj | Maximum junction temperature | 150 | °C | |
| R _{thja} | Thermal resistance junction to ambient SOT23-5 SO-8 | 250 150 | °C/W | |
| R _{thjc} | Thermal resistance junction to case SOT23-5 SO-8 | 80 28 | °C/W | |
| P _{max} | Maximum power dissipation ⁽⁴⁾ (@T _{amb} =25°C) for T _j =150°C SOT23-5 SO-8 | 500 830 | mW | |
| | HBM: human body model ⁽⁵⁾ pins 1, 4, 5, 6, 7 and 8 pins 2 and 3 | 2 0.5 | kV | |
| ESD | MM: machine model ⁽⁶⁾ pins 1, 4, 5, 6, 7 and 8 pins 2 and 3 | 200 60 | V | |
| | CDM: charged device model ⁽⁷⁾ pins 1, 4, 5, 6, 7 and 8 pins 2 and 3 | 1.5 1.5 | kV | |
| | Latch-up immunity | 200 | mA | |

- 1. All voltage values are measured with respect to the ground pin.
- 2. Differential voltage is the non-inverting input terminal with respect to the inverting input terminal.
- 3. The magnitude of input and output voltage must never exceed V_{CC} +0.3V.
- Short-circuits can cause excessive heating. Destructive dissipation can result from short-circuits on all amplifiers
- Human body model: A 100pF capacitor is charged to the specified voltage, then discharged through a 1.5kΩ resistor between two pins of the device. This is done for all couples of connected pin combinations while the other pins are floating.
- Machine model: A 200pF capacitor is charged to the specified voltage, then discharged directly between
 two pins of the device with no external series resistor (internal resistor < 5Ω). This is done for all couples of
 connected pin combinations while the other pins are floating.
- Charged device model: all pins and the package are charged together to the specified voltage and then discharged directly to the ground through only one pin. This is done for all pins.

Table 2. Operating conditions

| Symbol | Parameter | Value | Unit |
|-------------------|--------------------------------------|------------------------------------|------|
| V _{CC} | Supply voltage ⁽¹⁾ | 4.5 to 5.5 | V |
| V _{icm} | Common mode input voltage | $-V_{CC}$ +1.5V to $+V_{CC}$ -1.5V | V |
| T _{oper} | Operating free air temperature range | -40 to + 85 | °C |

^{1.} Tested in full production at 5V (±2.5V) supply voltage.

Electrical characteristics TSH350

2 Electrical characteristics

Table 3. Electrical characteristics for $V_{CC} = \pm 2.5V$, $T_{amb} = 25^{\circ}C$ (unless otherwise specified)

| Symbol | Parameter | Test conditions | Min. | Тур. | Max. | Unit | |
|----------------------|--|---|------|--------------------------|------|----------|--|
| DC performance | | | | | | | |
| \ / | Input offset voltage | T _{amb} | | 0.8 | 4 | \/ | |
| V_{io} | Offset voltage between both inputs | T _{min} < T _{amb} < T _{max} | | 1 | | mV | |
| ΔV_{io} | V _{io} drift vs. temperature | $T_{min} < T_{amb} < T_{max}$ | | 0.9 | | μV/°C | |
| 1 | Non inverting input bias current | T _{amb} | | 12 | 35 | μА | |
| I _{ib+} | DC current necessary to bias the input + | $T_{min} < T_{amb} < T_{max}$ | | 13 | | μΑ | |
| la | Inverting input bias current | T _{amb} | | 1 | 20 | μА | |
| I _{ib-} | DC current necessary to bias the input - | $T_{min} < T_{amb} < T_{max}$ | | 2.5 | | μν | |
| CMR | Common mode rejection ratio | $\Delta V_{ic} = \pm 1V$ | 56 | 60 | | dB | |
| OWIT | 20 log $(\Delta V_{ic}/\Delta V_{io})$ | $T_{min} < T_{amb} < T_{max}$ | | 58 | | QD | |
| SVR | Supply voltage rejection ratio | ΔV_{CC} =+3.5V to +5V | 68 | 81 | | dB | |
| OVIC | 20 log $(\Delta V_{\rm CC}/\Delta V_{\rm io})$ | $T_{min} < T_{amb} < T_{max}$ | | 78 | | ub | |
| PSR | Power supply rejection ratio | $A_V = +1$, $\Delta V_{CC} = \pm 100$ mV at 1kHz | | 51 | | dB | |
| | $20 \log (\Delta V_{\rm CC}/\Delta V_{\rm out})$ | $T_{min} < T_{amb} < T_{max}$ | | 48 | | <u> </u> | |
| I _{CC} | Positive supply current DC consumption with no input signal No load | | | 4.1 | 4.9 | mA | |
| Dynamic _I | performance and output characteristics | | | | | | |
| | Transimpedance | $\Delta V_{\text{out}} = \pm 1 V$, $R_L = 100 \Omega$ | 170 | 270 | | kΩ | |
| R _{OL} | Output voltage/input current gain in open loop of a CFA. For a VFA, the analog of this feature is the open loop gain (A _{VD}) | T _{min} < T _{amb} < T _{max} | | 250 | | kΩ | |
| Bw | -3dB bandwidth Frequency where the gain is 3dB below the DC gain A _V Note: Gain bandwidth product criterion is not applicable for current-feedback-amplifiers | $\begin{array}{l} \text{Small signal} \\ \text{V_{out}=$20m$V$_{pp}$} \\ \text{A_{V} = +1, R_{L} = 100Ω} \\ \text{A_{V} = +2, R_{L} = 100Ω} \\ \text{A_{V} = +10, R_{L} = 100Ω} \\ \text{A_{V} = -2, R_{L} = 100Ω} \end{array}$ | 250 | 550 390 125 370 | | MHz | |
| | Gain flatness @ 0.1dB Band of frequency where the gain variation does not exceed 0.1dB | Small signal V_{out} =100m V_{p} A_{v} = +1, R_{L} = 100 Ω | | 65 | | | |
| SR | Slew rate Maximum output speed of sweep in large signal | $V_{out} = 2V_{pp}, A_V = +2,$ $R_L = 100\Omega$ | | 940 | | V/µs | |
| V | High level output voltage | $R_L = 100\Omega$ | 1.44 | 1.56 | | V | |
| V _{OH} | High level output voltage | $T_{min} < T_{amb} < T_{max}$ | | 1.49 | | | |

Table 3. Electrical characteristics for $V_{CC} = \pm 2.5V$, $T_{amb} = 25^{\circ}C$ (unless otherwise specified)

| Table 3. | Liectrical characteristics for VCC - ±2.3V, Tamb - 23 C (unless otherwise specified) | | | | | | | |
|-----------------|---|--|------|--------------------------|-------|--------|--|--|
| Symbol | Parameter | Test conditions | Min. | Тур. | Max. | Unit | | |
| V. | Low level output voltage | $R_L = 100\Omega$ | | -1.53 | -1.44 | V | | |
| V _{OL} | Low level output voltage | $T_{min} < T_{amb} < T_{max}$ | | -1.49 | | | | |
| | I _{sink} | Output to GND | 135 | 205 | | | | |
| | Short-circuit output current coming in the opamp (see <i>Figure 9</i>) | $T_{min} < T_{amb} < T_{max}$ | | 195 | | mA | | |
| lout | I _{source} | Output to GND | -140 | -210 | | IIIA | | |
| | Output current coming out from the op-amp (see <i>Figure 10</i>) | $T_{min} < T_{amb} < T_{max}$ | | -185 | | | | |
| Noise and | distortion | | | | | | | |
| eN | Equivalent input noise voltage See Section 5: Noise measurements | F = 100kHz | | 1.5 | | nV/√Hz | | |
| :NI | Equivalent input noise current (+) See Section 5: Noise measurements | F = 100kHz | | 20 | | pA/√Hz | | |
| iN | Equivalent input noise current (-) See Section 5: Noise measurements | F = 100kHz | | 13 | | pA/√Hz | | |
| SFDR | Spurious free dynamic range The highest harmonic of the output spectrum when injecting a filtered sine wave | $\begin{aligned} A_V &= +1, \ V_{out} = 1 V_{pp} \\ F &= 10 MHz \\ F &= 20 MHz \\ F &= 50 MHz \\ F &= 100 MHz \end{aligned}$ | | -66 -57 -46 -42 | | dBc | | |

Table 4. Closed-loop gain and feedback components

| V _{CC} (V) | Gain | R _{fb} (Ω) | -3dB Bw (MHz) | 0.1dB Bw (MHz) |
|---------------------|------|---------------------|---------------|----------------|
| | +10 | 300 | 125 | 22 |
| | -10 | 300 | 120 | 20 |
| ±2.5 | +2 | 300 | 390 | 110 |
| ±2.5 | -2 | 300 | 370 | 70 |
| | +1 | 820 | 550 | 65 |
| | -1 | 300 | 350 | 120 |

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1G

Figure 1. Frequency response, positive gain Figure 2. Frequency response, negative gain



10M

Frequency (Hz)

Small Signal Vcc=5V

 $\text{Load=100}\Omega$

-10

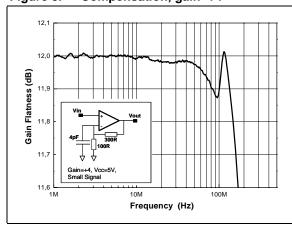


Figure 4. Compensation, gain=+2

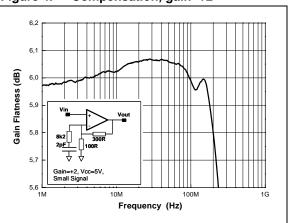
10M

Small Signal

Load=100 Ω

Vcc=5V

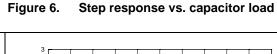
-10 ┗ 1M

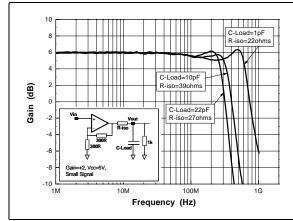


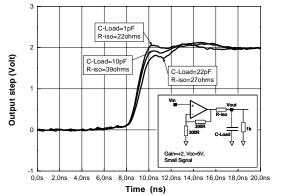
100M

Frequency (Hz)

Figure 5. Frequency response vs. capacitor Figure 10 load







TSH350 Electrical characteristics



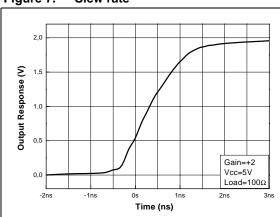


Figure 8. Output amplitude vs. load

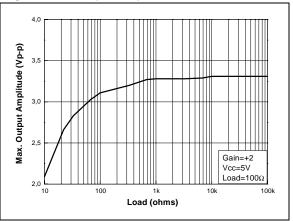


Figure 9. I_{sink}

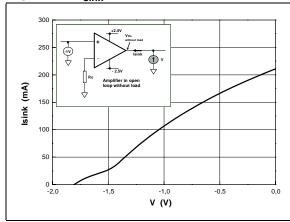


Figure 10. I_{source}

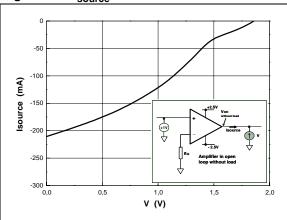


Figure 11. Input current noise vs. frequency

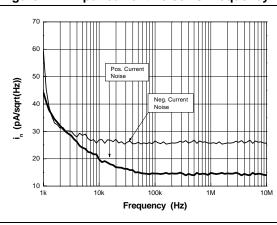
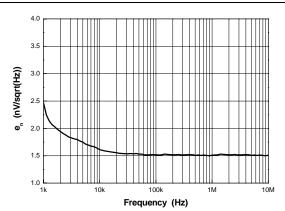


Figure 12. Input voltage noise vs. frequency



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Figure 13. Quiescent current vs. V_{CC}

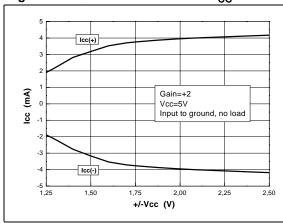


Figure 14. Distortion vs. output amplitude

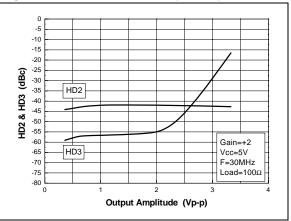


Figure 15. Distortion vs. output amplitude

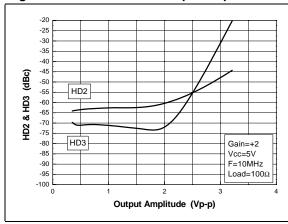


Figure 16. Noise figure

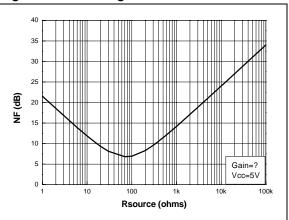


Figure 17. Distortion vs. output amplitude

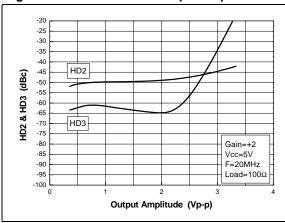


Figure 18. Output amplitude vs. frequency

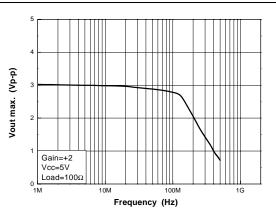


Figure 19. Reverse isolation vs. frequency

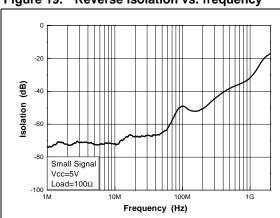


Figure 20. SVR vs. temperature

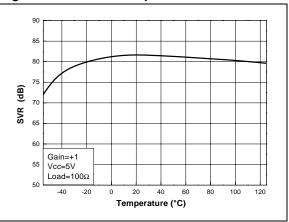


Figure 21. Bandwidth vs. temperature

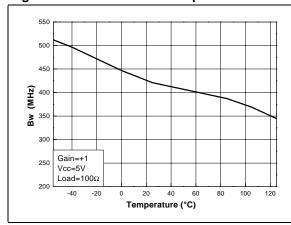


Figure 22. R_{OL} vs. temperature

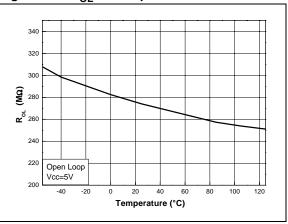


Figure 23. CMR vs. temperature

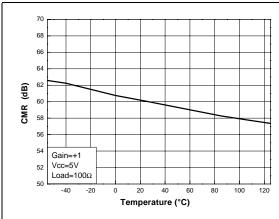
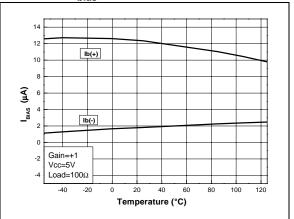


Figure 24. I_{bias} vs. temperature



Electrical characteristics TSH350

Figure 25. V_{io} vs. temperature

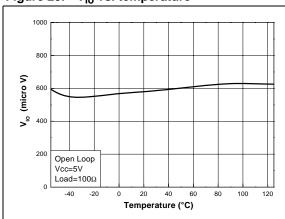


Figure 26. I_{CC} vs. temperature

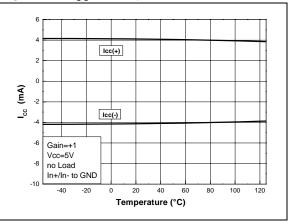


Figure 27. V_{OH} and V_{OL} vs. temperature

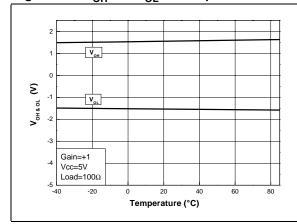
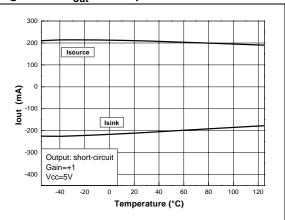


Figure 28. I_{out} vs. temperature



TSH350 Evaluation boards

3 Evaluation boards

An evaluation board kit optimized for high-speed operational amplifiers is available (order code: KITHSEVAL/STDL). As well as a CD-ROM containing datasheets, articles, application notes and a user manual, the kit includes the following evaluation boards:

- SOT23_SINGLE_HF BOARD
 Board for the evaluation of a single high-speed op-amp in SOT23-5 package.
- SO8_SINGLE_HF
 Board for the evaluation of a single high-speed op-amp in SO-8 package.
- SO8_DUAL_HF
 Board for the evaluation of a dual high-speed op-amp in SO-8 package.
- SO8_S_MULTI
 Board for the evaluation of a single high-speed op-amp in SO-8 package in inverting and non-inverting configuration, dual and single supply.
- SO14_TRIPLE
 Board for the evaluation of a triple high-speed op-amp in SO-14 package with video application considerations.

Board material:

- 2 layers
- FR4 (εr=4.6)
- epoxy 1.6mm
- copper thickness: 35μm





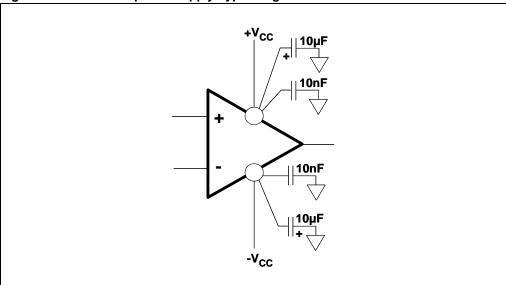
4 Power supply considerations

Correct power supply bypassing is very important for optimizing performance in high-frequency ranges. Bypass capacitors should be placed as close as possible to the IC pins to improve high-frequency bypassing. A capacitor greater than $1\mu F$ is necessary to minimize the distortion. For better quality bypassing, a capacitor of 10nF can be added which should also be placed as close as possible to the IC pins.

Bypass capacitors must be incorporated for both the negative and the positive supply.

Note: On the SO8_SINGLE_HF board, these capacitors are C6, C7, C8, C9.

Figure 30. Circuit for power supply bypassing



Single power supply

In the event that a single supply system is used, biasing is necessary to obtain a positive output dynamic range between 0V and +V $_{CC}$ supply rails. Considering the values of V $_{OH}$ and V $_{OL}$, the amplifier will provide an output swing from +0.9V to +4.1V on a 100 Ω load.

The amplifier must be biased with a mid-supply (nominally $+V_{CC}/2$), in order to maintain the DC component of the signal at this value. Several options are possible to provide this bias supply, such as a virtual ground using an operational amplifier or a two-resistance divider (which is the cheapest solution). A high resistance value is required to limit the current consumption. On the other hand, the current must be high enough to bias the non-inverting input of the amplifier. If we consider this bias current (35 μ A maximum) as 1% of the current through the resistance divider, to keep a stable mid-supply, two resistances of 750 Ω can be used.

The input provides a high-pass filter with a break frequency below 10Hz which is necessary to remove the original 0 volt DC component of the input signal, and to fix it at $+V_{CC}/2$.

Figure 31 illustrates a 5V single power supply configuration for the SO8_S_MULTI evaluation board (see *Evaluation boards* on page 11).

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A capacitor C_G is added in the gain network to ensure a unity gain in low frequency to keep the right DC component at the output. C_G contributes to a high-pass filter with $R_{fb}//R_G$ and its value is calculated with a consideration of the cut off frequency of this low-pass filter.

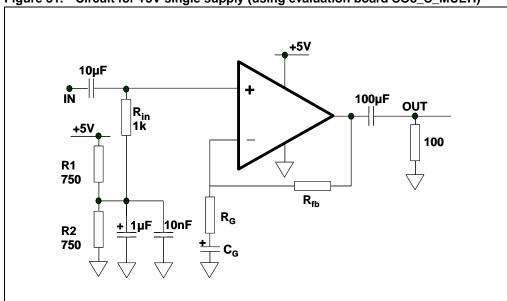


Figure 31. Circuit for +5V single supply (using evaluation board SO8_S_MULTI)

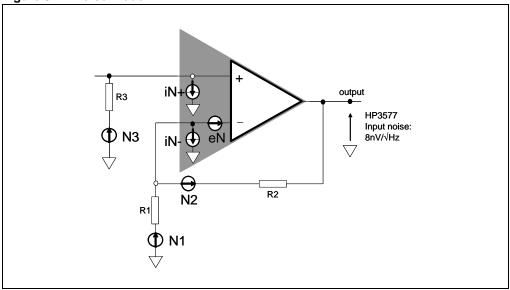
Noise measurements TSH350

5 Noise measurements

The noise model is shown in Figure 32:

- eN is the input voltage noise of the amplifier
- iNn is the negative input current noise of the amplifier
- iNp is the positive input current noise of the amplifier

Figure 32. Noise model



The thermal noise of a resistance R is

 $\sqrt{4kTR\Delta F}$

where ΔF is the specified bandwidth.

On a 1Hz bandwidth the thermal noise is reduced to:

√4kTR

where k is the Boltzmann's constant, equal to 1,374.10-23J/°K. T is the temperature (°K).

The output noise eNo is calculated using the Superposition Theorem. However, eNo is not the simple sum of all noise sources, but rather the square root of the sum of the square of each noise source, as shown in *Equation 1*:

Equation 1

$$eNo = \sqrt{V1^2 + V2^2 + V3^2 + V4^2 + V5^2 + V6^2}$$

TSH350 Noise measurements

Equation 2

$$eNo^2 = eN^2 \times g^2 + iNn^2 \times R2^2 + iNp^2 \times R3^2 \times g^2 + \frac{R2^2}{R1} \times 4kTR1 + 4kTR2 + 1 + \frac{R2^2}{R1} \times 4kTR3$$

The input noise of the instrumentation must be extracted from the measured noise value. The real output noise value of the driver is:

Equation 3

eNo =
$$\sqrt{\text{(Measured)}^2 - \text{(instrumentation)}^2}$$

The input noise is called **equivalent input noise** because it is not directly measured but is evaluated from the measurement of the output divided by the closed loop gain (eNo/g).

After simplification of the fourth and the fifth term of *Equation 2* we obtain:

Equation 4

$$eNo^{2} = eN^{2} \times g^{2} + iNn^{2} \times R2^{2} + iNp^{2} \times R3^{2} \times g^{2} + g \times 4kTR2 + 1 + \frac{R2^{2}}{R1} \times 4kTR3$$

Measurement of the input voltage noise eN

If we assume a short-circuit on the non-inverting input (R3=0), from *Equation 4* we can derive:

Equation 5

$$eNo = \sqrt{eN^2 \times g^2 + iNn^2 \times R2^2 + g \times 4kTR2}$$

In order to easily extract the value of eN, the resistance R2 will be chosen to be as low as possible. In the other hand, the gain must be large enough:

Measurement of the negative input current noise iNn

To measure the negative input current noise iNn, we set R3=0 and use *Equation 5*. This time, the gain must be lower in order to decrease the thermal noise contribution:

Measurement of the positive input current noise iNp

To extract iNp from *Equation 3*, a resistance R3 is connected to the non-inverting input. The value of R3 must be chosen in order to keep its thermal noise contribution as low as possible against the iNp contribution:

6 Intermodulation distortion product

The non-ideal output of the amplifier can be described by the following series:

$$V_{out} = C_0 + C_1 V_{in} + C_2 V_{in}^2 + ... + C_n V_{in}^n$$

where the input is V_{in} =Asin α t, C_0 is the DC component, $C_1(V_{in})$ is the fundamental and C_n is the amplitude of the harmonics of the output signal V_{out} .

A one-frequency (one-tone) input signal contributes to harmonic distortion. A two-tone input signal contributes to harmonic distortion and to the intermodulation product.

The study of the intermodulation and distortion for a two-tone input signal is the first step in characterizing the driving capability of multi-tone input signals.

In this case:

$$V_{in} = A \sin \omega_1 t + A \sin \omega_2 t$$

then:

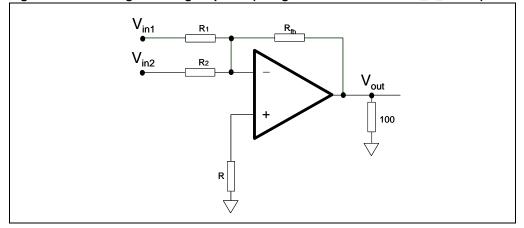
$$V_{out} = C_0 + C_1(A\sin\omega_1 t + A\sin\omega_2 t) + C_2(A\sin\omega_1 t + A\sin\omega_2 t)^2 ... + C_n(A\sin\omega_1 t + A\sin\omega_2 t)^n$$

From this expression, we can extract the distortion terms, and the intermodulation terms from a single sine wave:

- second order intermodulation terms IM2 by the frequencies (ω₁-ω₂) and (ω₁-ω₂) with an amplitude of C2A²
- third order intermodulation terms IM3 by the frequencies (2ω₁-ω₂), (2ω₁-ω₂), (-ω₁+2ω₂) and (ω₁-2ω₂) with an amplitude of (3/4)C3A³

The intermodulation product of the driver is measured by using the driver as a mixer in a summing amplifier configuration (see *Figure 33*). In this way, the non-linearity problem of an external mixing device is avoided.

Figure 33. Inverting summing amplifier (using evaluation board SO8_S_MULTI)



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7 Inverting amplifier biasing

A resistance is necessary to achieve good input biasing, such as resistance R shown in *Figure 34*.

The magnitude of this resistance is calculated by assuming the negative and positive input bias current. The aim is to compensate for the offset bias current, which could affect the input offset voltage and the output DC component. Assuming I_{ib-} , I_{ib+} , R_{in} , R_{fb} and a zero volt output, the resistance R is:

$$R = \frac{R_{in} \times R_{fb}}{R_{in} + R_{fb}}$$

Figure 34. Compensation of the input bias current

R_{fb}

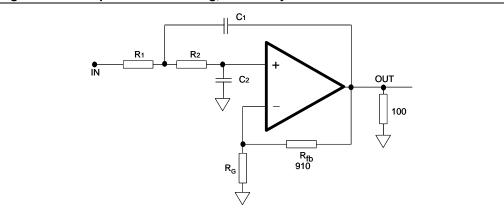
Output

Load

Active filtering TSH350

8 Active filtering

Figure 35. Low-pass active filtering, Sallen-Key



From the resistors R_{fb} and R_{G} we can directly calculate the gain of the filter in a classic non-inverting amplification configuration:

$$A_V \, = \, g \, = \, 1 + \frac{R_{fb}}{R_g}$$

We assume the following expression as the response of the system:

$$T_{j\omega} = \frac{Vout_{j\omega}}{Vin_{j\omega}} = \frac{g}{1 + 2\zeta\frac{j\omega}{\omega_{\!\!\!c}} + \frac{\left(j\omega\right)^2}{\omega_{\!\!\!c}^2}}$$

The cut-off frequency is not gain-dependent and so becomes:

$$\omega_c = \frac{1}{\sqrt{R1R2C1C2}}$$

The damping factor is calculated by the following expression:

$$\zeta \, = \, \frac{1}{2} \omega_{\!c} (C_1 R_1 + C_1 R_2 + C_2 R_1 - C_1 R_1 g)$$

The higher the gain, the more sensitive the damping factor is. When the gain is higher than 1, it is preferable to use some very stable resistor and capacitor values. In the case of R1=R2=R:

$$\zeta = \frac{2C_2 - C_1 \frac{R_{fb}}{R_g}}{2\sqrt{C_1 C_2}}$$

Due to a limited selection of values of capacitors in comparison with resistors, we can set C1=C2=C, so that:

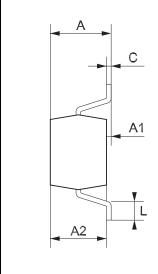
$$\zeta = \frac{2R_2 - R_1 \frac{R_{fb}}{R_g}}{2\sqrt{R_1 R_2}}$$

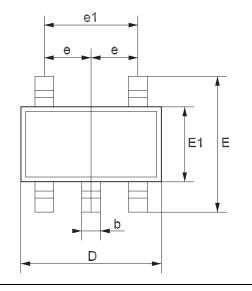
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Figure 36. SOT23-5 package mechanical data

| | Dimensions | | | | | |
|------|-------------|------|------|-------|------|-------|
| Ref. | Millimeters | | | Mils | | |
| | Min. | Тур. | Max. | Min. | Тур. | Max. |
| Α | 0.90 | | 1.45 | 35.4 | | 57.1 |
| A1 | 0.00 | | 0.15 | 0.00 | | 5.9 |
| A2 | 0.90 | | 1.30 | 35.4 | | 51.2 |
| b | 0.35 | | 0.50 | 13.7 | | 19.7 |
| С | 0.09 | | 0.20 | 3.5 | | 7.8 |
| D | 2.80 | | 3.00 | 110.2 | | 118.1 |
| E | 2.60 | | 3.00 | 102.3 | | 118.1 |
| E1 | 1.50 | | 1.75 | 59.0 | | 68.8 |
| е | | 0.95 | | | 37.4 | |
| e1 | | 1.9 | | | 74.8 | |
| L | 0.35 | | 0.55 | 13.7 | | 21.6 |

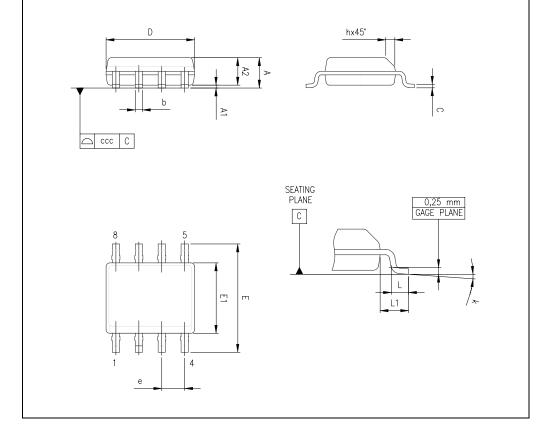




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Figure 37. SO-8 package mechanical data

| | Dimensions | | | | | |
|------|-------------|------|------|--------|-------|-------|
| Ref. | Millimeters | | | Inches | | |
| | Min. | Тур. | Max. | Min. | Тур. | Max. |
| А | | | 1.75 | | | 0.069 |
| A1 | 0.10 | | 0.25 | 0.004 | | 0.010 |
| A2 | 1.25 | | | 0.049 | | |
| b | 0.28 | | 0.48 | 0.011 | | 0.019 |
| С | 0.17 | | 0.23 | 0.007 | | 0.010 |
| D | 4.80 | 4.90 | 5.00 | 0.189 | 0.193 | 0.197 |
| Н | 5.80 | 6.00 | 6.20 | 0.228 | 0.236 | 0.244 |
| E1 | 3.80 | 3.90 | 4.00 | 0.150 | 0.154 | 0.157 |
| е | | 1.27 | | | 0.050 | |
| h | 0.25 | | 0.50 | 0.010 | | 0.020 |
| L | 0.40 | | 1.27 | 0.016 | | 0.050 |
| k | 1° | | 8° | 1° | | 8° |
| ccc | | | 0.10 | | | 0.004 |



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Table 5. Order codes

| Part number | Temperature range | Package | Packing | Marking |
|-------------|-------------------|---------|-------------|---------|
| TSH350ILT | | SOT23-5 | Tape & reel | K305 |
| TSH350ID | -40°C to +85°C | SO-8 | Tube | TSH350I |
| TSH350IDT | | SO-8 | Tape & reel | TSH350I |

11 Revision history

| Date | Revision | Changes |
|-------------|----------|--|
| 1-Oct-2004 | 1 | First release corresponding to Preliminary Data version of datasheet. |
| 10-Dec-2004 | 2 | Release of mature product datasheet. |
| 21-Jun-2005 | 3 | In <i>Table 1</i> on page 2, R _{thjc} thermal resistance junction to ambient replaced by thermal resistance junction to case. |
| 8-Jun-2007 | 4 | Format update. |

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